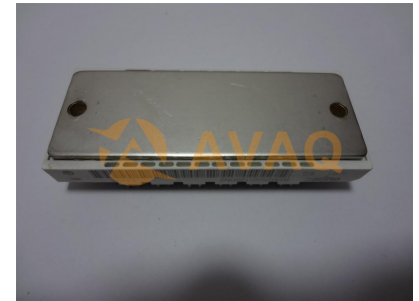


Trans IGBT Module N-CH 1200V 35A 200mW 17-Pin ECONO2-2



Images are for reference only

[Inquiry](#)

Manufacturer: [Infineon Technologies Corporation](#)

Package/Case: MODULE

Product Type: Thyristors

RoHS: RoHS Compliant/Lead free 

Lifecycle: Unconfirmed

General Description

Key Features

3-phase Full bridge

130ns Rise time

100ns Fall time

±20V Gate-emitter voltage



Recommended For You

BSS223PWH6327XTSA1

Infineon Technologies Corporation
SOT-323

BSP315PH6327XTSA1

Infineon Technologies Corporation
SOT-223

BSS138NH6327XTSA2

Infineon Technologies Corporation
SOT23

BSS123NH6327XTSA1

Infineon Technologies Corporation
SOT-23

BSMB00GB120DLC

Infineon Technologies Corporation
MODULE

BSM200GB120DLC

Infineon Technologies Corporation
MODULE

BSM75GD120DLC

Infineon Technologies Corporation
IGBT

BSS816NWH6327XTSA1

Infineon Technologies Corporation
SOT-323

BSMB00GA170DN2

Infineon Technologies Corporation
MODULE

BSMI5GD120DN2

Infineon Technologies Corporation
MODULE

BSMB5GP120

Infineon Technologies Corporation
MODULE

BSM25GD120DN2E3224

Infineon Technologies Corporation
MODULE

BSMB00GA120DN2

Infineon Technologies Corporation
MODULE

BSM400GA170DLC

Infineon Technologies Corporation
MODULE

BSM50GP120

Infineon Technologies Corporation
MODULE